



DMT6016LPS

60V N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

BV _{DSS}	Rds(on)	I _D Tc = +25°C
60V	15mΩ @ V _{GS} = 10V	32A
60 V	24mΩ @ Vgs = 4.5V	24A

Description and Applications

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) and maintain superior switching performance, making it ideal for highefficiency power-management applications.

- Load switches
- Adaptor switches
- Notebook PCs

Features

- 100% Unclamped Inductive Switching (UIS) Test in Production -Ensures More Reliable and Robust End Application
- Thermally Efficient Package Cooler Running Applications
- High Conversion Efficiency
- Low RDS(ON) Minimizes On-State Losses
- Low Input Capacitance
- Fast Switching Speed
- <1.1mm Package Profile Ideal for Thin Applications
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Package: PowerDI5060-8
- Package Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208 (3)
- Terminal Connections: See Diagram Below
- Weight: 0.097 grams (Approximate)



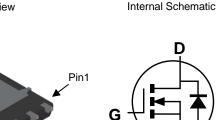
Site 2:

Notes:

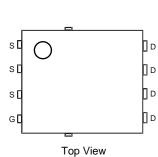


Bottom View

PowerDI5060-8/SWP (Type UX)



G



Pin Configuration

Ordering Information (Note 4)

Part Number	Packaga		Packing		
Fait Nulliper	Package	Qty.	Carrier		
DMT6016LPS-13	PowerDI5060-8	2,500	Tape & Reel		
DMT6016LPS-13	PowerDI5060-8/SWP (Type UX)	2,500	Tape & Reel		

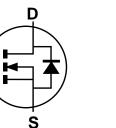
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

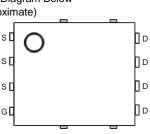
4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

sí s G Top View Pin Configuration



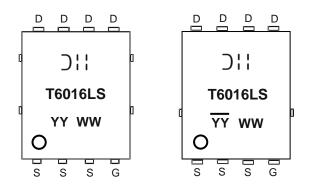
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Internal Schematic





Marking Information



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	60	V
Gate-Source Voltage			Vgss	±20	V
Continuous Drain Current (Note 6) $V_{GS} = 10V$ $T_C = +25^{\circ}C$ $T_C = +70^{\circ}C$			ID	32 25	A
Continuous Drain Current (Note 5) V _{GS} = 10V	Steady State	T _A = +25°C T _A = +70°C	ID	10 8	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			Ідм	120	А
Maximum Continuous Body Diode Forward Current (Note 6)			ls	27	А
Avalanche Current (Note 7) L = 0.1mH			I _{AS}	15.3	А
Avalanche Energy (Note 7) L = 0.1mH			Eas	11.7	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T _A = +25°C	PD	2.6	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	RθJA	49	°C/W
Total Power Dissipation (Note 6)	Tc = +25°C	PD	26	W
Thermal Resistance, Junction to Ambient (Note 6)		Rejc	4.8	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.

6. Thermal resistance from junction to soldering point (on the exposed drain pad). 7. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep $T_J = +25^{\circ}C$.

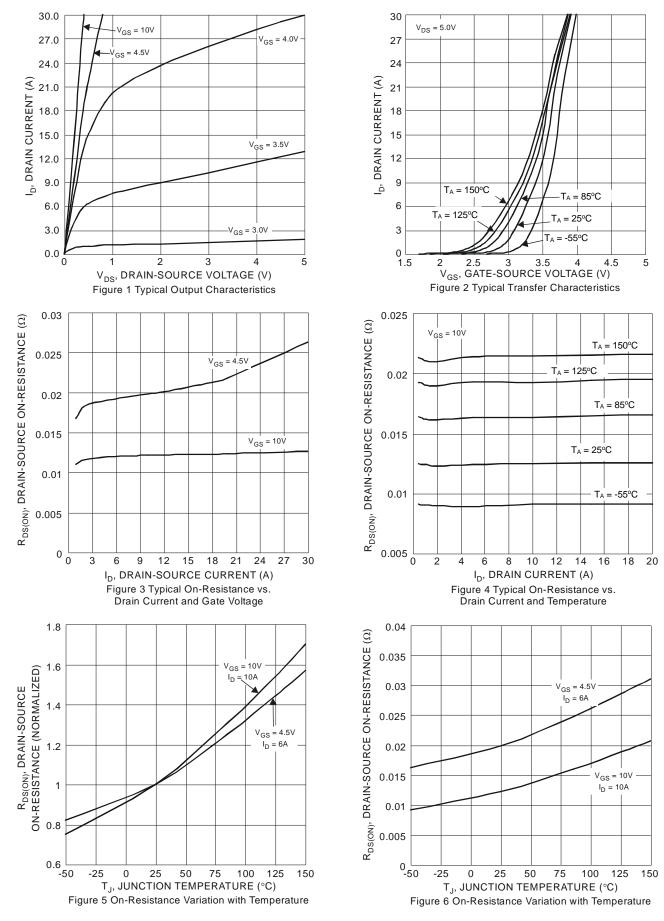


Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Ob any stanistic	0		T	M	11	To at Oam dition
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)	I		1	1		
Drain-Source Breakdown Voltage	BV _{DSS}	60	—	—	V	$V_{GS} = 0V, I_D = 250\mu A$
Zero Gate Voltage Drain Current	IDSS		—	1	μA	$V_{DS} = 48V, V_{GS} = 0V$
Gate-Source Leakage	lgss	_	—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)				•		
Gate Threshold Voltage	VGS(TH)	1	—	2.5	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$
Static Drain-Source On-Resistance	Descent		—	15	mΩ	$V_{GS} = 10V, I_D = 20A$
Static Drain-Source On-Resistance	RDS(ON)	_	—	24	11122	VGS = 4.5V, ID = 18A
Diode Forward Voltage	V _{SD}	_	0.7	1.2	V	$V_{GS} = 0V, I_{S} = 1A$
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	Ciss	—	864	-	pF	$V_{DS} = 30V, V_{GS} = 0V,$ f = 1MHz
Output Capacitance	Coss	_	282	_		
Reverse Transfer Capacitance	Crss	—	27	-		
Gate Resistance	Rg	_	1.3	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	8.4	_		
Total Gate Charge (V _{GS} = 10V)	Qg	—	17	-	nC	V _{DS} = 30V, I _D = 10A
Gate-Source Charge	Qgs	_	3.1	_		
Gate-Drain Charge	Q _{gd}	_	4.3	_		
Turn-On Delay Time	t _{D(ON)}		3.4	_		
Turn-On Rise Time	tR		5.2	_	ns	$\label{eq:VGS} \begin{array}{l} V_{GS} = 10V, V_{DS} = 30V, \\ R_G = 6\Omega, I_D = 10A \end{array}$
Turn-Off Delay Time	tD(OFF)	_	13	_		
Turn-Off Fall Time	tF	_	7	_	1	
Reverse Recovery Time	trr		22	—	ns	
Reverse Recovery Charge	Qrr		11	—	nC	I _F = 10A, di/dt = 100A/μs

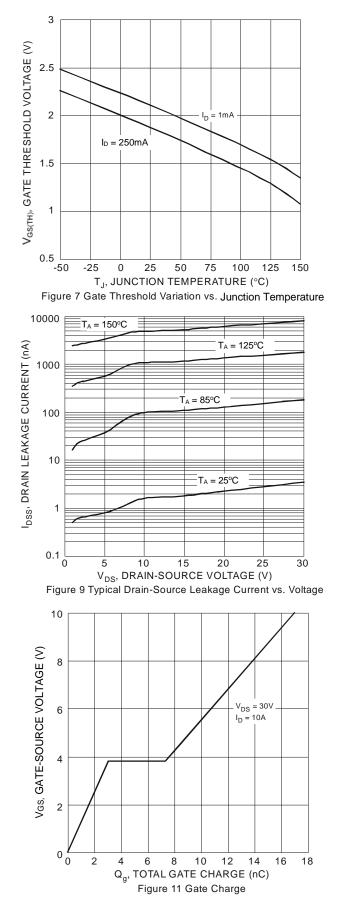
8. Short duration pulse test used to minimize self-heating effect.9. Guaranteed by design. Not subject to product testing. Notes:

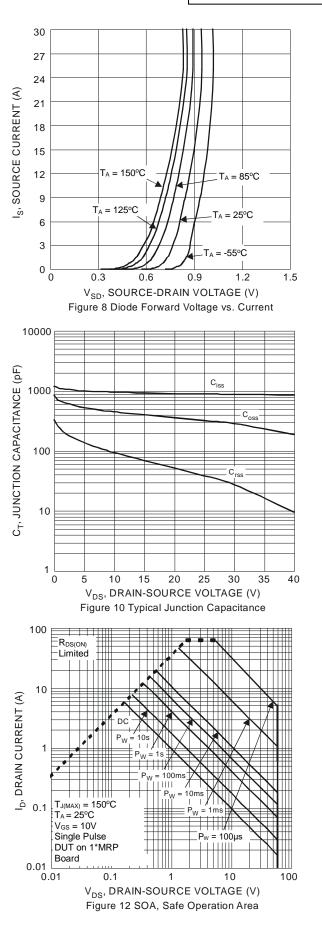




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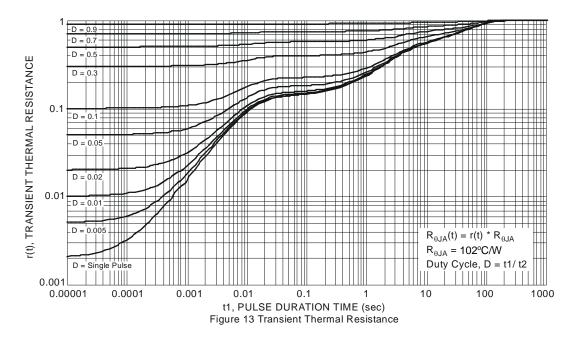






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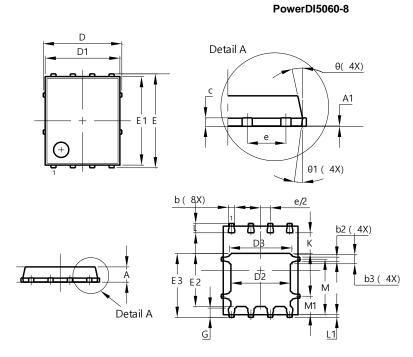




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

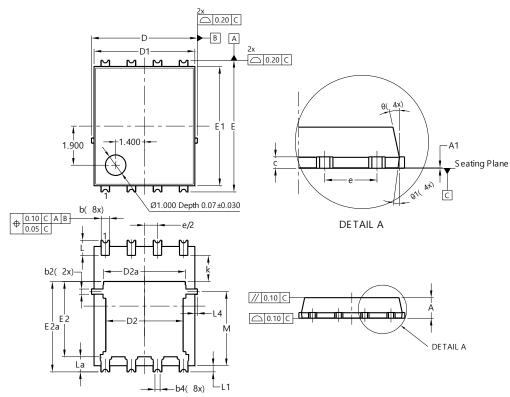
Site1:



	PowerDI5060-8					
Dim	Min	Max	Тур			
Α	0.90	1.10	1.00			
A1	0.00	0.05				
b	0.33	0.51	0.41			
b2	0.200	0.350	0.273			
b3	0.40	0.80	0.60			
С	0.230	0.330	0.277			
D		5.15 BSC	;			
D1	4.70	5.10	4.90			
D2	3.70	4.10	3.90			
D3	3.90	4.30	4.10			
E	6.15 BSC					
E1	5.60	6.00	5.80			
E2	3.28	3.68	3.48			
E3	3.99	4.39	4.19			
е	1.27 BSC					
G	0.51	0.71	0.61			
K	0.51					
L	0.51	0.71	0.61			
L1	0.100	0.200	0.175			
М	3.235	4.035	3.635			
M1	1.00	1.40	1.21			
Θ	10°	12°	11°			
Θ1	6°	8°	7°			
Al	All Dimensions in mm					

Site2:

PowerDI5060-8/SWP (Type UX)



Po	PowerDI5060-8/SWP (Type UX)				
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0	0.05			
b	0.30	0.50	0.41		
b2	0.20	0.35	0.25		
b4).25REF			
С	0.230	0.330	0.277		
D	-	.15 BS0	2		
D1	4.70	5.10	4.90		
D2	3.56	3.96	3.76		
D2a	3.78	4.18	3.98		
E	6	6.40 BS0	2		
E1	5.60	6.00	5.80		
E2	3.46	3.86	3.66		
E2a	4.195	4.595	4.395		
е	1	1.27BSC)		
k	1.05				
L	0.635	0.835	0.735		
La	0.635	0.835	0.735		
L1	0.200	0.400	0.300		
L4	0.025	0.225	0.125		
М	3.205	4.005	3.605		
θ	10°	12°	11°		
θ1	6°	8°	7°		
All	All Dimensions in mm				

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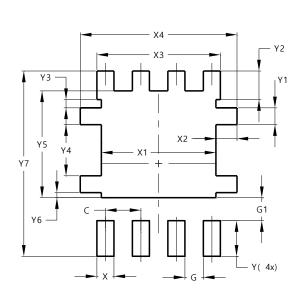


Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

Site1:

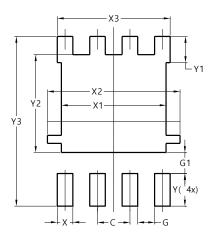




Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	0.755
X3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610

Site 2:

PowerDI5060-8/SWP (Type UX)



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	5.190
X3	4.420
Y	1.270
Y1	1.020
Y2	3.810
Y3	6.610



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